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1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol		Value	Unit			
V_{RRM}	Repetitive peak reverse vol	tage			45	V
I _{F(RMS)}	Forward rms voltage				30	Α
I _{F(AV)}	Average forward current	TO-220AB / D ² PAK / I ² PAK / TO-247	T _c = 155 °C	Per diode Per device	15	А
$\delta = 0.5$	$\delta = 0.5$	TO-220FPAB	T _c = 130 °C		30	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$				220	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s, T_j = 25 \text{ °C}$					W
T _{stg}	Storage temperature range					°C
T _j	Maximum operating junctio	+175	°C			
T _j	Maximum operating junctio (DC forward current without	200	°C			
dV/dt	Critical rate of rise reverse	10000	V/µs			

^{1.} $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance parameters

Symbol		Parameter				
		TO-220AB / D ² PAK / I ² PAK	Per diode Total	1.60 0.95		
R _{th (j-c)}	Junction to case	TO-247	Per diode Total	1.5 0.9	°C/W	
		TO-220FPAB	Per diode Total	4 3.2		
R _{th (c)}	Coupling	TO-220AB / D ² PAK / I ² PAK / TO-247		0.30	°C/W	
	Coupling	TO-220FPAB		2.5	-0/00	

When the diodes 1 and 2 are used simultaneously: $\Delta T_j(\text{diode 1}) = P(\text{diode1}) \; x \; R_{th(j\text{-}c)}(\text{Per diode}) \; + \; P(\text{diode2}) \; x \; R_{th(c)}$

STPS3045C Characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$			200	μΑ
'R`′		T _j = 125 °C			11	40	mA
V _F ⁽¹⁾	Forward voltage drop	T _j = 125 °C	I _F = 15 A		0.5	0.57	
		T _j = 25 °C	I _F = 30 A			0.84	V
		T _j = 125 °C			0.65	0.72	

Table 4. Static electrical characteristics (per diode)

To evaluate the conduction losses use the following equation:

$$P = 0.42 \text{ x } I_{F(AV)} + 0.01 I_{F}^{2}_{(RMS)}$$

Figure 1. Average forward power dissipation versus average forward current (per diode)

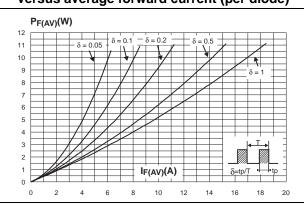


Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode)

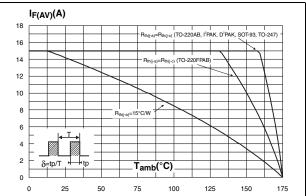
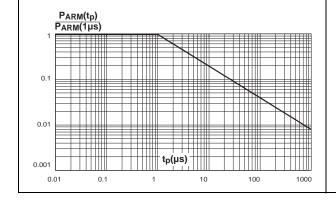
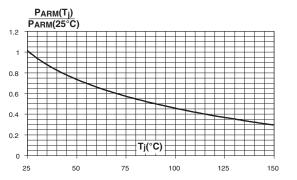


Figure 3. Normalized avalanche power derating versus pulse duration versus junction temperature



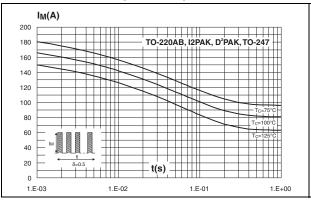


^{1.} Pulse test: t_p = 380 μ s, δ < 2%

Characteristics STPS3045C

Figure 5. Non repetitive surge peak forward current versus overload duration (max. values, current versus overload duration (max. values, per diode)

Figure 6. Non repetitive surge peak forward per diode, TO-220FPAB)



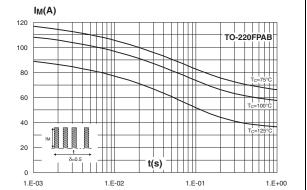
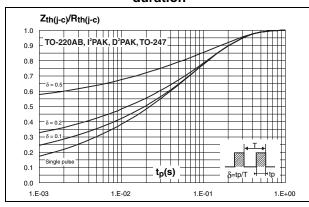


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration

Figure 8. Relative variation of thermal impedance junction to ambient versus pulse duration (TO-220FPAB)



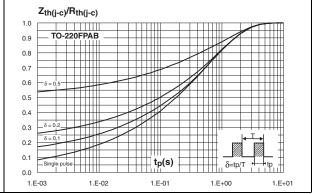
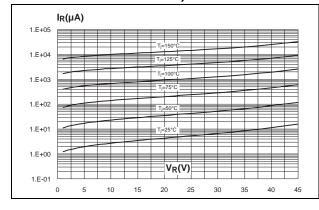
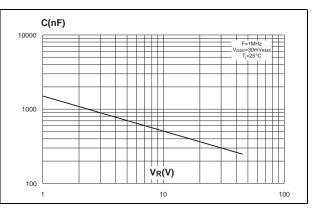


Figure 9. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)



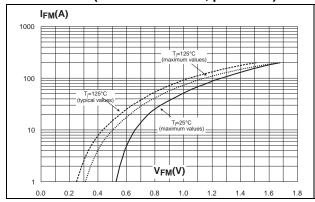


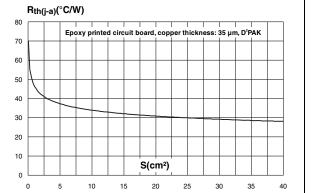
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Figure 11. Forward voltage drop versus forward current (maximum values, per diode)

Figure 12. Thermal resistance junction to ambient versus copper surface under tab







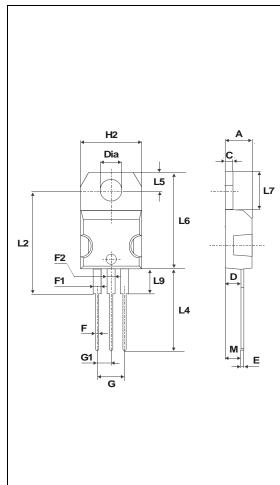
Package information STPS3045C

2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N⋅m (TO-220AB, TO-220FPAB)
- Recommended torque value: 0.55 to 1.0 N·m (TO-247)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB dimensions



	Dimensions					
Ref.	Millin	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.40	4.60	0.173	0.181		
С	1.23	1.32	0.048	0.051		
D	2.40	2.72	0.094	0.107		
Е	0.49	0.70	0.019	0.027		
F	0.61	0.88	0.024	0.034		
F1	1.14 1.70		0.044	0.066		
F2	1.14	1.70	0.044	0.066		
G	4.95	5.15	0.194	0.202		
G1	2.40	2.70	0.094	0.106		
H2	10	10.40	0.393	0.409		
L2	16.4	typ.	0.645 typ.			
L4	13	14	0.511	0.551		
L5	2.65	2.95	0.104	0.116		
L6	15.25	15.75	0.600	0.620		
L7	6.20	6.60	0.244	0.259		
L9	3.50	3.93	0.137	0.154		
М	2.6	typ.	0.102	2 typ.		
Diam.	Diam. 3.75 3.85		0.147	0.151		

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STPS3045C Package information

Devices in I²PAK with nickel-plated back frame must NOT be mounted by frame soldering like SMDs. Such devices are intended to be through-hole mounted ONLY and in no circumstances shall ST be held liable for any lack of performance or damage arising out of soldering of nickel-plated back frames.

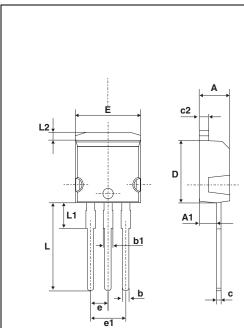


Table 6. I²PAK dimensions

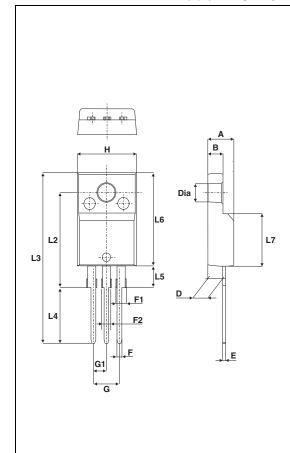
	Dimensions					
Ref.	Millin	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.40	4.60	0.173	0.181		
A1	2.40	2.72	0.094	0.107		
b	0.61	0.88	0.024	0.035		
b1	1.14	1.70	0.044	0.067		
С	0.49	0.70	0.019	0.028		
c2	1.23	1.32	0.048	0.052		
D	8.95	9.35	0.352	0.368		
е	2.40	2.70	0.094	0.106		
e1	4.95	5.15	0.195 0.203			
Е	10	10.40	0.394	0.409		
L	13	14	0.512	0.551		
L1	3.50	3.93	0.138 0.158			
12	1 27	1 40	0.050	0.055		



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Table 7. TO-220FPAB dimensions

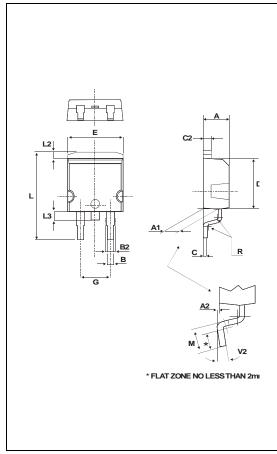


	Dimensions					
Ref.	Millim	neters	Inches			
	Min. Max.		Min.	Max.		
Α	4.4	4.6	0.173	0.181		
В	2.5	2.7	0.098	0.106		
D	2.5	2.75	0.098	0.108		
Е	0.45	0.70	0.018	0.027		
F	0.75	1	0.030	0.039		
F1	1.15	1.70	0.045	0.067		
F2	1.15	1.70	0.045	0.067		
G	4.95	5.20	0.195	0.205		
G1	2.4	2.7	0.094	0.106		
Н	10	10.4	0.393	0.409		
L2	16	Гур.	0.63	3 Тур.		
L3	28.6	30.6	1.126	1.205		
L4	9.8	10.6	0.386	0.417		
L5	2.9	3.6	0.114	0.142		
L6	15.9	16.4	0.626	0.646		
L7	9.00	9.30	0.354	0.366		
Dia.	3.00	3.20	0.118	0.126		

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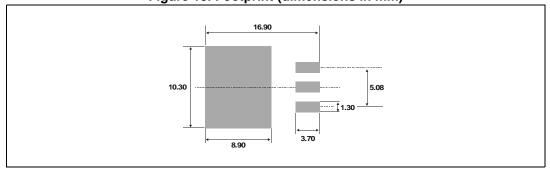
STPS3045C Package information

Table 8. D²PAK dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.40	4.60	0.173	0.181		
A1	2.49	2.69	0.098	0.106		
A2	0.03	0.23	0.001	0.009		
В	0.70	0.93	0.027	0.037		
B2	1.14	1.70	0.045	0.067		
С	0.45	0.60	0.017	0.024		
C2	1.23	1.36	0.048	0.054		
D	8.95	9.35	0.352	0.368		
Е	10.00	10.40	0.393	0.409		
G	4.88	5.28	0.192	0.208		
L	15.00	15.85	0.590	0.624		
L2	1.27	1.40	0.050	0.055		
L3	1.40	1.75	0.055	0.069		
М	2.40	3.20	0.094	0.126		
R	0.40 typ.		0.016	6 typ.		
V2	0°	8°	0°	8°		

Figure 13. Footprint (dimensions in mm)



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Package information STPS3045C

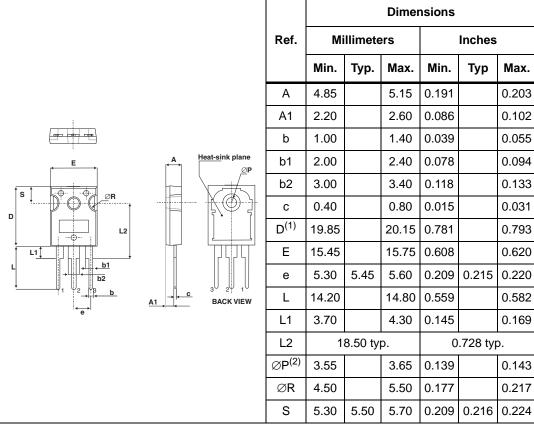


Table 9. TO-247 dimensions

- 1. Dimension D plus gate protrusion does not exceed 20.5 mm
- 2. Resin thickness around the mounting hole is not less than 0.9 mm

3 Ordering information

Table 10. Ordering information

Order code Marking		Package	Weight	Base qty	Delivery mode
STPS3045CT	STPS3045CT STPS3045CT TO-220AB		2.23 g	50	Tube
STPS3045CR STPS3045		I ² PAK	1.49 g	50	Tube
STPS3045CFP STPS30450		TO-220FPAB	2.0 g	50	Tube
STPS3045CG	STPS3045CG STPS3045CG		1.48 g	50	Tube
STPS3045CG-TR	STPS3045CG	D ² PAK	1.46 g	1000	Tape and reel
STPS3045CW STPS3045CW		TO-247	4.46 g	30	Tube

4 Revision history

Table 11. Document revision history

Date	Revision	Changes
July-2003	6E	Last update.
06-Nov-2012	7	Removed SOT-93 and TOP-3I packages. <i>Table 2</i> : Operating range (T _j) extension from -40 to +175° C, I _{F(AV)} per diode updated to 15 A. Updated "Total" values in <i>Table 3</i> . Updated tables in <i>Section 2</i> : <i>Package information</i> .
04-Apr-2013	8	Added value for maximum T _j in forward mode. Updated <i>Table 9</i> .

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